# **Surface Mount Chip Terminations**

### CZ1 Style

# WXX

#### **GENERAL SPECIFICATIONS**

• Nominal Impedance: 50 Ω

· Resistive Tolerance: ±2% standard

• Operating Temp Range: -55 to +150°C

· Temperature Coefficient: ±150 ppm/°C

· Resistive Elements: Tantalum, Thin Film Processed

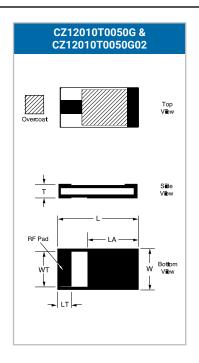
Substrate Material: Aluminum Nitride

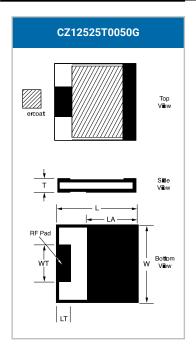
· Terminals: Silver over Nickel

· Lead-Free, RoHS Compliant

• Reliability: MIL-PRF-55342

· Tape & Reel Specifications:

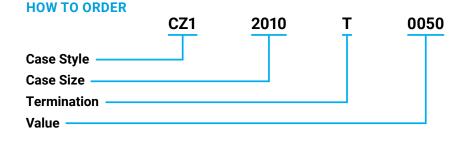


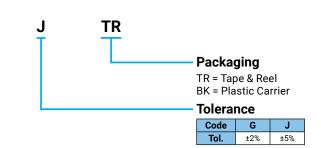


mm

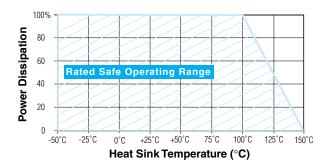
Part Number	W ±.010	L ±.010	T ±.005	LT ±.005	WT ±.005	LA ±.005	Frequency Range (GHz)	VSWR (Typ.)	Power Max* (Watts)
CZ12010T0050G	.100	.200	.040	.040	.090	.115	DC - 3.0	1.20:1	10W
CZ12010T0050G02	.100	.200	.040	.020	.090	.140	DC - 3.0	1.20:1	10W
CZ12525T0050G	.245	.245	.040	.030	.125	.170	DC - 4.0	1.25:1	20W

<sup>\*</sup> Test Condition: Chip soldered to a via patch on a 30-mil-thick Rogers RO4350 board; Land surfaces at 100° C; maximum rated power applied. Specification: The resistance of the film shall change no more than 0.5% during and after a 1000-hr. Burn-in per Mil-PRF-55342.





### **POWER DERATING**



# **Surface Mount Chip Terminations**

### **CZ1 Style**

# XXV

### **GENERAL SPECIFICATIONS**

• Nominal Impedance: 50 Ω

Resistive Tolerance: ±2% standard

• Operating Temp Range: -55 to +150°C

· Temperature Coefficient: ±150 ppm/°C

· Resistive Elements: Tantalum, Thin Film Processed

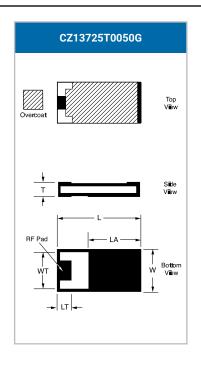
· Substrate Material: Aluminum Nitride

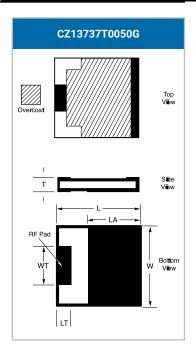
· Terminals: Silver over Nickel

· Lead-Free, RoHS Compliant

• Reliability: MIL-PRF-55342

· Tape & Reel Specifications:



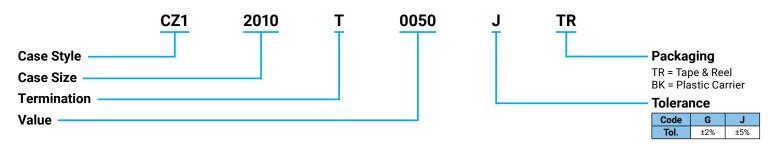


mm

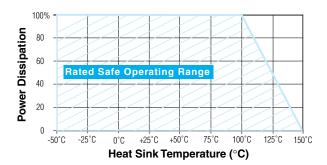
Part Number	W ±.010	L ±.010	T ±.005	LT ±.005	WT ±.005	LA ±.005	Frequency Range (GHz)	VSWR (Typ.)	Power Max* (Watts)
CZ13725T0050G	.250	.375	.040	.050	.125	.260	DC - 2.2	1.20:1	30W
CZ13737T0050G	.370	.370	.040	.050	.125	.275	DC - 3.0	1.25:1	40W

<sup>\*</sup> Test Condition: Chip soldered to a via patch on a 30-mil-thick Rogers RO4350 board; Land surfaces at 100° C; maximum rated power applied. Specification: The resistance of the film shall change no more than 0.5% during and after a 1000-hr. Burn-in per Mil-PRF-55342.

### **HOW TO ORDER**



### **POWER DERATING**



# 单击下面可查看定价,库存,交付和生命周期等信息

## >>AVX